TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHCT373AF,TC74VHCT373AFW,TC74VHCT373AFT

Octal D-Type Latch with 3-State Output

The TC74VHCT373A is an advanced high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type latch is controlled by a latch enable input (LE) and a output enable input (\overline{OE}).

When the \overline{OE} input is high, the eight outputs are in a high impedance state.

The input voltage are compatible with TTL output voltage. This device may be used as a level converter for interfacing $3.3\ V$ to $5\ V$ system.

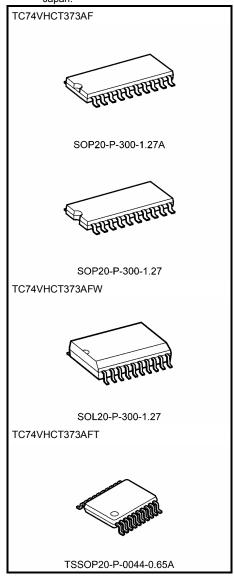
Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output $^{\rm (Note)}$ pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: Output in off-state

Features

- High speed: $t_{pd} = 7.7$ ns (typ.) at $V_{CC} = 5$ V
- Low power dissipation: $ICC = 4 \mu A \text{ (max)}$ at $Ta = 25^{\circ}C$
- Power down protection is provided on all inputs and outputs.
- Balanced propagation delays: t_pLH ≃ t_pHL
- Low noise: VOLP = 1.6 V (max)
- Pin and function compatible with the 74 series (74AC/HC/F/ALS/LS etc.) 373 type.

Note: xxxFW (JEDEC SOP) is not available in Japan.



Weight

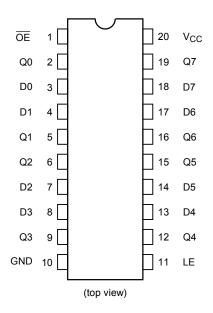
 SOP20-P-300-1.27A
 : 0.22 g (typ.)

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 : 0.22 g (typ.)

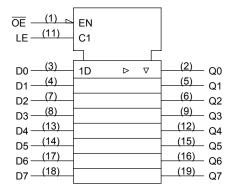
 SOL20-P-300-1.27
 : 0.46 g (typ.)

 TSSOP20-P-0044-0.65A
 : 0.08 g (typ.)

Pin Assignment



IEC Logic Symbol



Truth Table

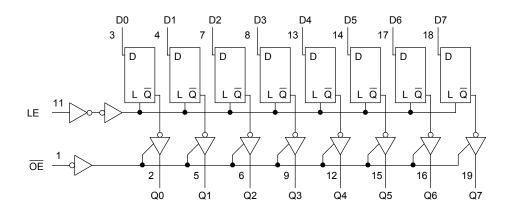
	Inputs		Output
ŌE	LE	D	Output
Н	Х	Х	Z
L	L	Х	Q _n
L	Н	L	L
L	Н	Н	Н

X: Don't care

Z: High impedance

 $\mathsf{Q}_{\mathsf{n}} . \, \mathsf{Q}$ outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram





Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	−0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
DC output voltage	\/a	-0.5 to 7.0 (Note 2)	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	±20 (Note 4)	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	P_{D}	180	mW
Storage temperature	T _{stg}	−65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: Output in off-state

Note 3: High or low state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Recommended Operating Conditions (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5 to 5.5	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to 5.5 (Note 2)	V
Output voltage	VOU1	0 to V _{CC} (Note 3)	
Operating temperature	T _{opr}	−40 to 85	°C
Input rise and fall time	dt/dV	0 to 20	ns/V

Note 1: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

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Note 2: Output in off-state

Note 3: High or low state



Electrical Characteristics

DC Characteristics

Characteristics	Symbol		Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
				V _{CC} (V)	Min	Тур.	Max	Min	Max	
High-level input voltage	V _{IH}	_		4.5 to 5.5	2.0	_	-	2.0	_	V
Low-level input voltage	V _{IL}		_	4.5 to 5.5	_	_	0.8	_	0.8	V
High-level output	\/	V _{IN}	I _{OH} = -50 μA	4.5	4.40	4.50	_	4.40	_	V
voltage	Voн	= V _{IH} or V _{IL}	I _{OH} = -8 mA	4.5	3.94	_	-	3.80	_	
Low-level output voltage		V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	_	0.0	0.1	_	0.1	٧
	V _{OL}		I _{OL} = 8 mA	4.5	1	_	0.36	_	0.44	
3-state output off-state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5	_	_	±0.25	_	±2.50	μΑ
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1	_	±1.0	μΑ
	Icc	V _{IN} = V _C	V _{IN} = V _{CC} or GND		_	_	4.0	_	40.0	μA
Quiescent supply current	Ісст	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	_	1.35	_	1.50	mA
Output leakage current	I _{OPD}	V _{OUT} = 5	5.5 V	0			0.5		5.0	μΑ

Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 to 85°C	Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width (LE)	t _{w (H)}	_	5.0 ± 0.5	_	6.5	8.5	ns
Minimum set-up time	ts	_	5.0 ± 0.5	_	1.5	1.5	ns
Minimum hold time	t _h	_	5.0 ± 0.5	_	3.5	3.5	ns

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AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
			V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
Propagation delay time	t _{pLH}	_	5.0 ± 0.5	15	_	7.7	12.3	1.0	13.5	ns
(LE-Q)	t_{pHL}		0.0 2 0.0	50		8.5	13.3	1.0	14.5	113
Propagation delay time	t _{pLH}	_	5.0 ± 0.5	15	1	5.1	8.5	1.0	9.5	ns
(D-Q)	t_{pHL}	_	5.0 ± 0.5	50	_	5.9	9.5	1.0	10.5	
3-state output enable	t _{pZL}	R _L = 1 kΩ	5.0 ± 0.5	15		6.3	10.9	1.0	12.5	ns
time	^t pZH			50	1	7.1	11.9	1.0	13.5	
3-state output disable time	t _{pLZ}	R _L = 1 kΩ	5.0 ± 0.5	50	_	8.8	11.2	1.0	12.0	ns
Output to output skew	t _{osLH}	(Note 1)	5.0 ± 0.5	50	_	_	1.0	_	1.0	ns
Input capacitance	C _{IN}		_		_	4	10	_	10	pF
Output capacitance	C _{OUT}		_		_	9	_	_	_	pF
Power dissipation capacitance	C _{PD}			(Note 2)	-	25	-	_	_	pF

Note 1: Parameter guaranteed by design.

 $t_{OSLH} = |t_{DLHm} - t_{DLHn}|, t_{OSHL} = |t_{DHLm} - t_{DHLn}|$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 (per latch)$$

And the total C_{PD} when n pcs. of latch operate can be gained by the following equation:

 C_{PD} (total) = 14 + 11·n

Noise Characteristics (input: $t_r = t_f = 3$ ns) (Note)

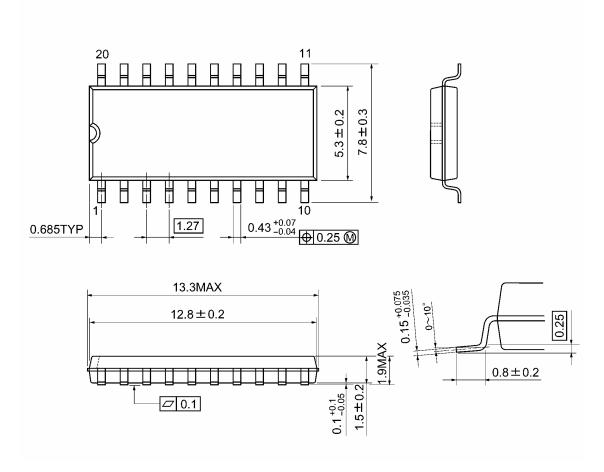
Characteristics	Symbol	Test Condition		Ta = 25°C		Unit
Gharacteristics	Symbol		V _{CC} (V)	Тур.	Max	Oill
Quiet output maximum dynamia V	V	0 50 75	5.0	1.1	1.5	V
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF		(1.2)	(1.6)	
Quiet output minimum dynamic V	V _{OLV}	C _L = 50 pF	5.0	-1.1	-1.5	V
Quiet output minimum dynamic V _{OL}				(-1.2)	(-1.6)	
Minimum high level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	_	2.0	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	-	0.8	٧

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Note: The value in () only applies to JEDEC SOP (FW) devices.

Package Dimensions

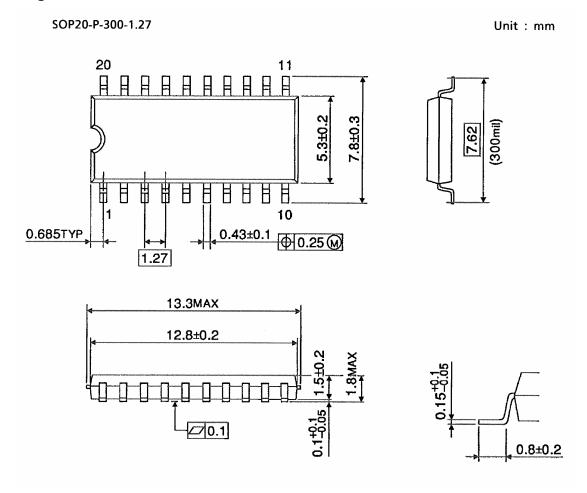
SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)



Package Dimensions

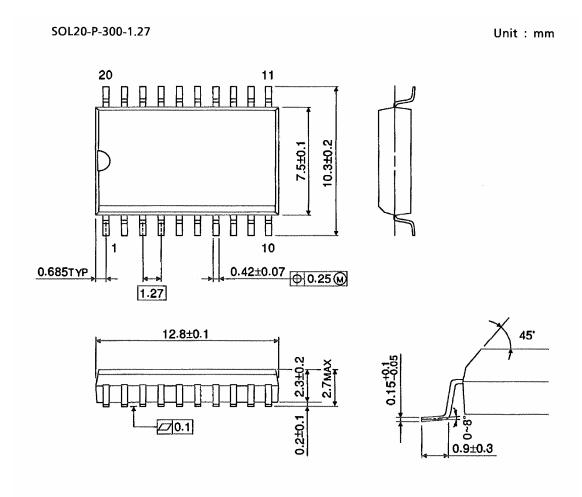


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Weight: 0.22 g (typ.)



Package Dimensions (Note)



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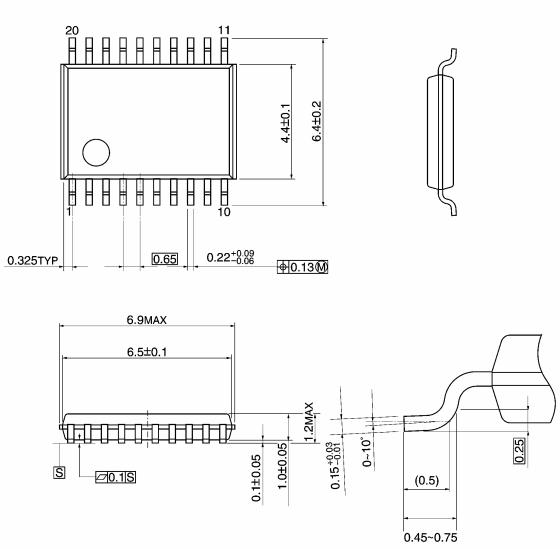
Note: This package is not available in Japan.

Weight: 0.46 g (typ.)



Package Dimensions

TSSOP20-P-0044-0.65A Unit: mm



Weight: 0.08 g (typ.)

Note: Lead (Pb)-Free Packages

SOP20-P-300-1.27A TSSOP20-P-0044-0.65A

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